HD14008B

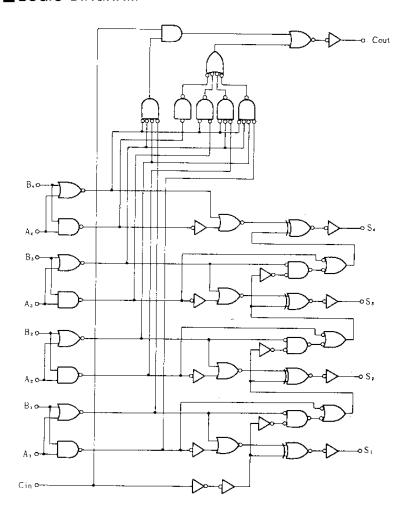
4-bit Full Adder

The HD14008B 4-bit full adder consists of four full adders with fast internal look-ahead carry output. It is useful in binary addition and other arithmetic applications. The fast parallel carry output bit allows high-speed operation when used with other adders in a system.

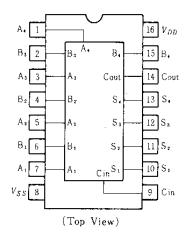
■ FEATURES

- Look-Ahead Carry Output
- High-Speed Operation; 160ns typ. from Sumin to Sumout
- Quiescent Current; 5nA/pkg typ @5V
- Supply Voltage Range = 3 to 18V
- Pin-for-Pin Replacement for CD4008B and MC14008B

■LOGIC DIAGRAM



■ PIN ARRANGEMENT



■ TRUTH TABLE(1 Stage)

Cin	В	A	Cout	S
0	0	0	0	0
0	0	1	0	1
0	1	0	0	1
0	1	1	1	0
1	0	0	0	1
1	0	1	1	0
1	1	0	1	0
1	I	1	1	1

■ ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Test Conditions		- 40°C		25° C		85° ℃		Unit		
Characteristic		$V_{DD}(V)$	rest Conditions	min	max	min	typ	max	min	max	Omi	
Output Voltage		5.0		_	0.05	!	0	0.05	-	0.05	v	
	Vol	10	$V_{i\pi} = V_{DD}$ or 0		0.05	<u> </u>	0	0.05		0.05		
		15		_	0.05	-	0	0.05	_	0.05		
		5.0		4.95		4.95	5.0	_	4.95		v	
	V_{OH}	10	$V_{in}=0$ or V_{DD}	9.95	:	9.95	10	_	9.95			
		15		14.95	= 7.	14.95	15		14.95	-		
16		5.0	$V_{out} = 4.5 \text{ or } 0.5 \text{V}$	_	1.5	1	2.25	1.5		1.5	v	
	V_{IL}	10	$V_{ extsf{out}} = 9.0 ext{ or } 1.0 ext{V}$	_	3.0	_	4.50	3.0	_ '	3.0		
Input Voltage		15	$V_{out} = 13.5 \text{ or } 1.5 \text{V}$	-	4.0	_	6.75	4.0		4.0		
input voitage		5.0	$V_{out} = 0.5 \text{ or } 4.5 \text{V}$	3.5		3.5	2.75	_	3.5	_	v	
	V_{IH}	10	$V_{out}=~1.0~{ m or}~~9.0{ m ilde{V}}$	7.0		7.0	5.50	_	7.0			
		15	$V_{out} = 1.5 \text{ or } 13.5 \text{V}$	11.0	-	11.0	8.25	_	11.0	*		
Output Drive Current	Іон	5.0	$V_{OH}=2.5\mathrm{V}$	-1.0		-0.8	-1.7		-0.6			
		5.0	$V_{OH} = 4.6 \mathrm{V}$	-0.2	_	-0.16	-0.36	_	-0.12		mA	
		10	$V_{OH} = 9.5.V$ -0.5 -0.4		-0.9	_	-0.3	_				
		15	$V_{OH}=13.5\mathrm{V}$	-1.4	_	-1.2	-3.5		-1.0	_	.	
	IoL	5.0	$V_{OL} = 0.4 \text{ V}$	0.52	_	0.44	0.88	_	0.36			
		10	$V_{OL} = 0.5 \mathrm{V}$	1.3	_	1.1	2.25	_	0.9	_	m A	
		15	$V_{OL} = 1.5 \mathrm{V}$	3.6	_	3.0	8.8	-	2.4			
Input Current	Iin	15		_	±0.3	<u> </u>	±0.00001	±0.3		±1.0	μΑ	
Input Capacitance	Cin] -]	$V_{in}=0$	_	_		5.0	7.5	_		рF	
Quiescent Current	I _{DD}	5.0	7 \$1		20		0.005	20	<u> </u>	150	-	
		10	Zero Signal,	_	40	_	0.010	40		300		
		15	per Package		80	_	0.015	80	_	600	· 	
Total Supply Current*		5.0	Dynamic $+I_{DD}$, $C_L = 50$ pF	_	_		1.7	_	·	_	_	
	I_T	10	f=1 kHz,	_	_	_	3.4			200		
		15	Per Gate	_	_	_	5.0	<u> </u>	j –	-		

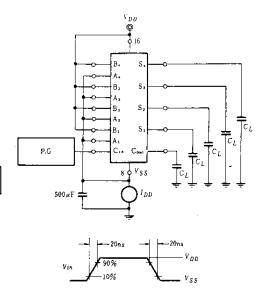
^{*} To calculate total supply current at frequency other than lkHz. $@Vop=5.0V \quad I\tau = (1.7\mu\text{A/kHz})f + Ioo \qquad @Vop=10V \quad I\tau = (3.4\mu\text{A/kHz})f + Ioo \qquad @Vvo-15V \quad I\tau = (5.0\mu\text{A/kHz})f - Ioo$

■DC CHARACTERISTIC TEST CIRCUIT

$\bullet I_{\mathit{OH}}$ $\bullet I_{\mathit{OL}}$

V_{DD}=-V_{GS} V_{out} V_{DD}=V_{GS} V_{out} V_{DD}=V_{GS} V_{out} I6 B. S. A. B. S. A. B. S. A. B. S. A. B. S. A. A. B. S. A. A. B. S. A. B. S. A. B. S. A. B. S. A. A. B. S. A.

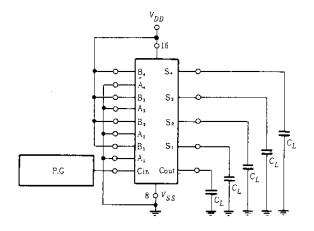
●POWER DISSIPATION TEST CIRCUIT AND WAVEFORM

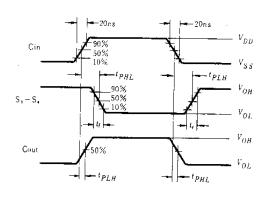


ESWITCHING CHARACTERISTICS $(C_L = 50 \text{pF}, Ta = 25 ^{\circ}\text{C})$

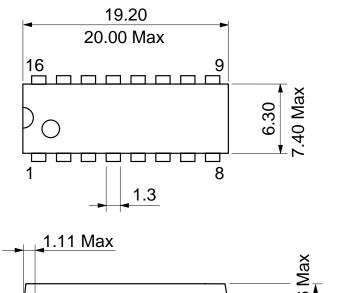
Character	istic	Symbol	$V_{DD}(V)$	min	typ	max	Unit	
Output Rise Time			5.0		180	360		
		tτ	10	-	90	180	ns	
			15		65	130		
Output Fall Time		tf	5.0		100	200	ns	
			10	_	50	100		
			15		40	80		
Propagation Delay Time	Sum In-to-		5.0		400	800		
	Sum Out Sum In-to- Carry Out	: i i	10		160	320		
			15	_	115	230		
			5.0	-	305	610		
			10	. —	145	290	1	
		t₽LH,	15		110	220		
		t PHL	5.0		375	750	ns	
			į	10		155	310	
			15		115	230		
	Carry In-		5.0		170	340		
		:	10		75	150		
	Carry Out		15		55	110		

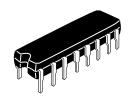
■ SWITCHING TIME TEST CIRCUIT

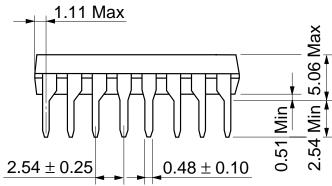


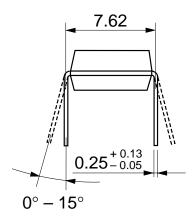


Unit: mm









Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g

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